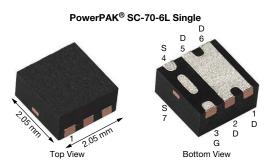
Vishay Siliconix

# N-Channel 60 V (D-S) MOSFET



PRODUCT SUMMARY								
V <sub>DS</sub> (V)	60							
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = 10 \text{ V}$	0.0185							
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = 7.5 \text{ V}$	0.0225							
Q <sub>g</sub> typ. (nC)	6.9							
I <sub>D</sub> (A)	12 <sup>a, g</sup>							
Configuration	Single							

#### **FEATURES**

- TrenchFET® Gen IV power MOSFET
- Very low R<sub>DS</sub> Q<sub>g</sub> Figure-of-Merit (FOM)
- Tuned for the lowest R<sub>DS</sub> Q<sub>oss</sub>
- 100 % R<sub>a</sub> and UIS tested
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

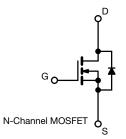


RoHS COMPLIANT

HALOGEN FREE

#### **APPLICATIONS**

- Primary side switch
- Synchronous rectification
- DC/DC converters
- · Motor drive switch
- Boost converter
- · LED backlighting



ORDERING INFORMATION					
Package	PowerPAK SC-70				
Lead (Pb)-free and halogen-free	SiA106DJ-T1-GE3				

ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>A</sub> = 25 °C, u	ınless otherwis	se noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V <sub>DS</sub>	60	V
Gate-source voltage		$V_{GS}$	± 20	V
	T <sub>C</sub> = 25 °C		12 <sup>a</sup>	
Continuous dusin surrent /T 150 °C)	T <sub>C</sub> = 70 °C	1 , $ extstyle  e$	12 <sup>a</sup>	
Continuous drain current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> =25 °C	I <sub>D</sub>	10 b, c	
	T <sub>A</sub> = 70 °C		8.1 <sup>b, c</sup>	
Pulsed drain current (t = 100 μs)	I <sub>DM</sub>	40	Α	
	T <sub>C</sub> = 25 °C		12 <sup>a</sup>	
Continuous source-drain diode current	T <sub>A</sub> = 70 °C	I <sub>S</sub>	2.9 b, c	
Single pulse avalanche current	1 0111	I <sub>AS</sub>	12	
Single pulse avalanche energy	L = 0.1 mH	E <sub>AS</sub>	7.2	mJ
	T <sub>C</sub> = 25 °C		19	
Maximum power dissipation	T <sub>C</sub> = 70 °C		12	14/
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.5 <sup>b, c</sup>	W
	T <sub>A</sub> = 70 °C		2.2 b, c	
Operating junction and storage temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	
Soldering recommendations (peak tempera		260		

THERMAL RESISTANCE RATINGS									
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT				
Maximum junction-to-ambient b, f	t ≤ 5 s	R <sub>thJA</sub>	28	36	°C/W				
Maximum junction-to-case (drain)	Steady state	R <sub>thJC</sub>	5.3	6.5	C/VV				

## Notes

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board
- c. t = 5 s
- d. See solder profile (<a href="www.vishay.com/ppg?73257">www.vishay.com/ppg?73257</a>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- f. Maximum under steady state conditions is 80 °C/W
- g.  $T_C = 25 \, ^{\circ}C$



# Vishay Siliconix

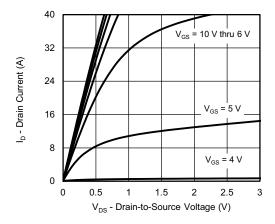
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static					l .	
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60	-	-	V
V <sub>DS</sub> temperature coefficient	$\Delta V_{DS}/T_{J}$	L 050 A	-	35	-	
V <sub>GS(th)</sub> temperature coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = 250 \mu\text{A}$	-	-7.1	-	mV/°
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2	-	4	V
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	100	nA
7		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	_
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 70 °C	-	=	10	μA
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	10	-	-	Α
<b>.</b>	_	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4 A	-	0.0142	0.0185	
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 7.5 \text{ V}, I_D = 4 \text{ A}$	-	0.0166	0.0225	Ω
Forward transconductance a	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 10 A	-	25	-	S
Dynamic <sup>b</sup>					L	
Input capacitance	C <sub>iss</sub>		-	540	-	pF
Output capacitance	C <sub>oss</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	150	-	
Reverse transfer capacitance	C <sub>rss</sub>		-	11	-	
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4 A	-	8.9	13.5	nC
Total gate charge	$Q_g$		-	6.9	10.5	
Gate-source charge	Q <sub>qs</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 7.5 \text{ V}, I_D = 4 \text{ A}$	-	2.5	-	
Gate-drain charge	Q <sub>qd</sub>		-	1.8	-	
Output charge	Q <sub>oss</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	-	9	-	
Gate resistance	Ra	f = 1 MHz	0.3	1.3	2.6	Ω
Turn-on delay time	t <sub>d(on)</sub>		-	10	20	
Rise time	t <sub>r</sub>	$V_{DD} = 30 \text{ V}, \text{ R}_L = 7.5 \Omega, \text{ I}_D \cong 4 \text{ A},$	-	5	10	ns
Turn-off delay time	t <sub>d(off)</sub>	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	14	30	
Fall time	t <sub>f</sub>		-	5	10	
Turn-on delay time	t <sub>d(on)</sub>		-	10	20	
Rise time	t <sub>r</sub>	$V_{DD} = 30 \text{ V}, R_1 = 7.5 \Omega, I_D \cong 4 \text{ A},$	-	5	10	
Turn-off delay time	t <sub>d(off)</sub>	$V_{GEN} = 7.5 \text{ V}, R_g = 1 \Omega$	-	12	25	
Fall time	t <sub>f</sub>		-	5	10	
<b>Drain-Source Body Diode Characteristi</b>	cs		1			
Continuous source-drain diode current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	-	-	12	
Pulse diode forward current	I <sub>SM</sub>		-	-	40	A
Body diode voltage	V <sub>SD</sub>	I <sub>S</sub> = 4 A, V <sub>GS</sub> = 0 V	-	0.85	1.2	V
Body diode reverse recovery time	t <sub>rr</sub>		-	38	75	ns
Body diode reverse recovery charge	Q <sub>rr</sub>		-	23	45	nC
Reverse recovery fall time	ta	$I_F = 4 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$	-	17	-	
Reverse recovery rise time	t <sub>b</sub>		-	21	-	ns

#### **Notes**

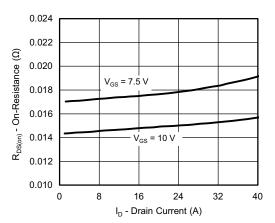
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

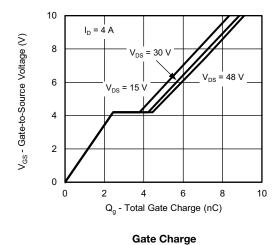


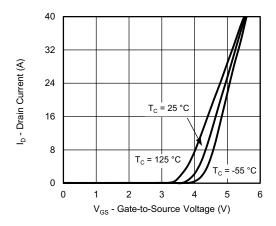


#### **Output Characteristics**

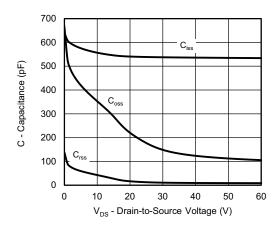


On-Resistance vs. Drain Current and Gate Voltage

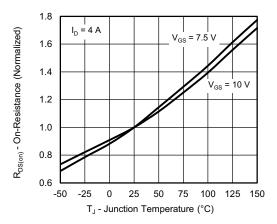




**Transfer Characteristics** 

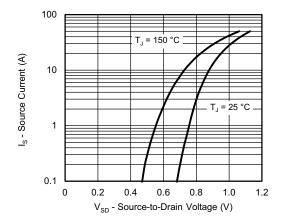


Capacitance

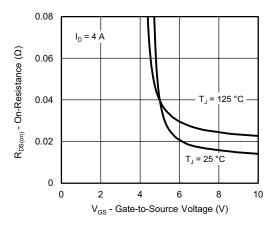


On-Resistance vs. Junction Temperature

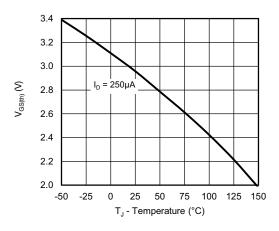




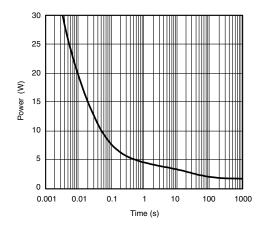
Source-Drain Diode Forward Voltage



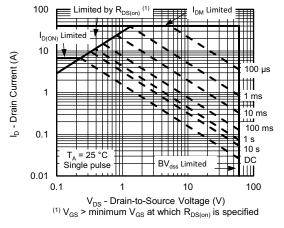
On-Resistance vs. Gate-to-Source Voltage



**Threshold Voltage** 

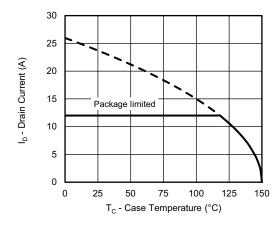


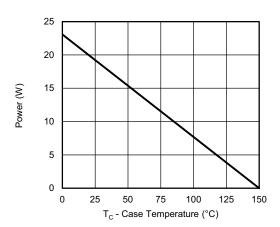
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient







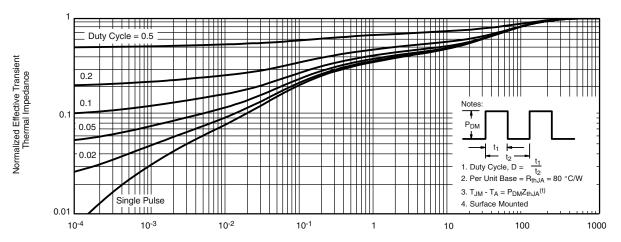
Current Derating a

Power, Junction-to-Case

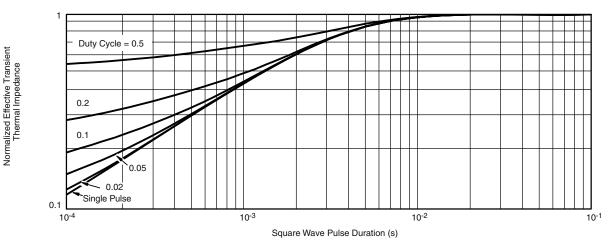
#### Note

a. The power dissipation P<sub>D</sub> is based on T<sub>J</sub> max. = 25 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

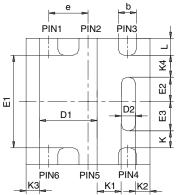
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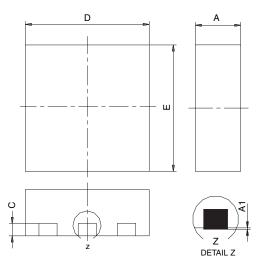
# PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
  Package outline exclusive of mold flash and metal burr
  Package outline inclusive of plating

	SINGLE PAD						DUAL PAD					
DIM	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
Е	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;	0.65 BSC			0.026 BSC		
K		0.275 TYP			0.011 TYP		0.275 TYP			0.011 TYP		
K1		0.400 TYP		0.016 TYP			0.320 TYP			0.013 TYP		
K2		0.240 TYP		0.009 TYP		0.252 TYP			0.010 TYP			
К3		0.225 TYP		0.009 TYP						•	•	
K4		0.355 TYP		0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
T							0.05	0.10	0.15	0.002	0.004	0.006

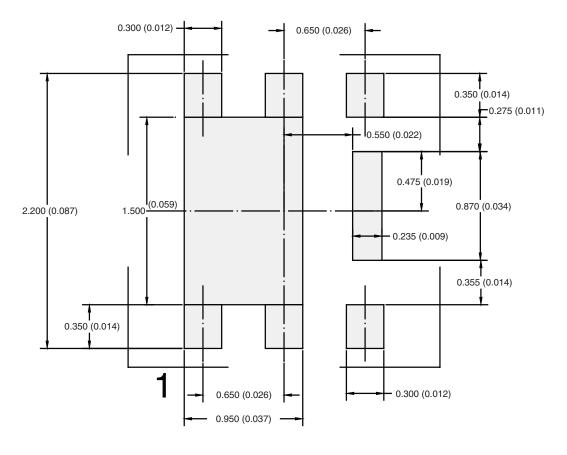
ECN: C-07431 - Rev. C, 06-Aug-07

DWG: 5934

06-Aug-07



# RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

Return to Index

ATTLICATION NOT



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Vishay

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